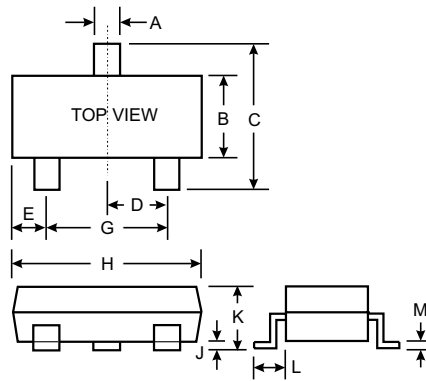


Features

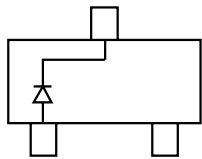
- Low Turn-on Voltage
- Fast Switching
- PN Junction Guard Ring for Transient and ESD Protection

Mechanical Data

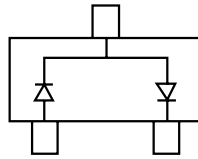
- Case: SOT-23, Molded Plastic
- Terminals: Solderable per MIL-STD-202, Method 208
- Polarity: See Diagrams
- Approx. Weight: 0.008 grams



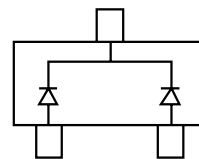
SOT-23		
Dim	Min	Max
A	0.37	0.51
B	1.19	1.40
C	2.10	2.50
D	0.89	1.05
E	0.45	0.61
G	1.78	2.05
H	2.65	3.05
J	0.013	0.15
K	0.89	1.10
L	0.45	0.61
M	0.076	0.178
All Dimensions in mm		



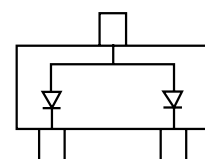
BAS70H Marking: K73



BAS70H-04 Marking: K74



BAS70H-05 Marking: K75



BAS70H-06 Marking: K76

Maximum Ratings and Electrical Characteristics, Single Diode @ T_A = 25°C unless otherwise specified

Characteristic	Symbol	BAS70	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V_{RRM} V_{RWM} V_R	70	V
RMS Reverse Voltage	$V_{R(RMS)}$	49	V
Forward Continuous Current (Note 1)	I_F	200	mA
Non-Repetitive Peak Forward Surge Current @ $t_p < 1.0s$	I_{FSM}	600	mA
Power Dissipation (Note 1)	P_d	200	mW
Thermal Resistance Junction to Ambient Air (Note 1)	$R_{\theta JA}$	625	K/W
Operating and Storage Temperature Range	T_j	-55 to +125	°C
Storage Temperature Range	T_{STG}	-65 to +150	°C

Electrical Ratings

@ T_A = 25°C unless otherwise specified

Characteristic	Symbol	Min	Max	Unit	Test Condition
Reverse Breakdown Voltage (Note 2)	$V_{(BR)R}$	70	—	V	$I_R = 10\mu A$
Forward Voltage	V_F	—	410 1000	mV	$t_p < 300\mu s, I_F = 1.0mA$ $t_p < 300\mu s, I_F = 15mA$
Peak Reverse Current	I_{RM}	—	100	nA	$t_p < 300\mu s, V_R = 50V$
Junction Capacitance	C_j	—	2.0	pF	$V_R = 0V, f = 1.0MHz$
Reverse Recovery Time	t_{rr}	—	5.0	ns	$I_F = I_R = 10mA$ to $I_R = 1.0mA$, $R_L = 100\Omega$

Notes: 1. Valid Provided that terminals are kept at ambient temperature.
2. Test period <3000μs.